



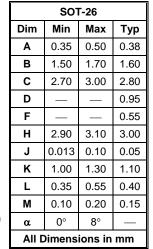
# DMMT5401

#### MATCHED PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

#### **Features**

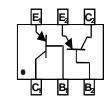
- **Epitaxial Planar Die Construction**
- Complementary NPN Type Available (DMMT5551)
- Ideal for Low Power Amplification and Switching
- Intrinsically Matched PNP Pair (Note 1)
- 2% Matched Tolerance, hFE, VCE(SAT), VBE(SAT)
- Lead Free/RoHS Compliant (Note 4)
- "Green" Device (Note 5 and 6)

# В



#### **Mechanical Data**

- Case: SOT-26
- Case Material: Molded Plastic, "Green" Molding Compound, Note 6. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Copper leadframe).
- Marking Information: K4S, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-160	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-150	V
Emitter-Base Voltage	$V_{EBO}$	-5.0	V
Collector Current - Continuous (Note 2)	I <sub>C</sub>	-200	mA
Power Dissipation (Note 2, 3)	P <sub>d</sub>	300	mW
Thermal Resistance, Junction to Ambient (Note 2)	$R_{ hetaJA}$	417	°C/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

#### Notes:

- Built with adjacent die from a single wafer. 1.
- Device mounted on FR5 PCB: 1.0 x 0.75 x 0.62 in.; pad layout as shown on suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 3. Maximum combined dissipation.
- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

  Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

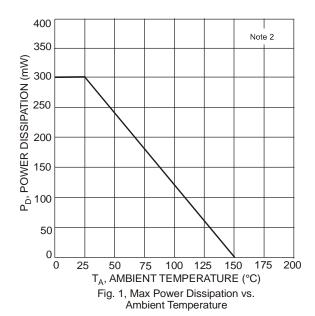


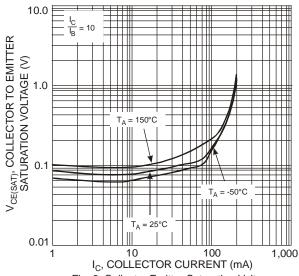
#### **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-160	_	V	$I_C = -100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	-150		٧	$I_C = -1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	-5.0		V	$I_E = -10\mu A, I_C = 0$
Collector Cutoff Current	I <sub>CBO</sub>		-50	nA μA	$V_{CB} = -120V, I_{E} = 0$ $V_{CB} = -120V, I_{E} = 0, T_{A} = 100^{\circ}C$
Emitter Cutoff Current	I <sub>EBO</sub>	_	-50	nA	$V_{EB} = -3.0V, I_C = 0$
ON CHARACTERISTICS (Note 7)					
		50	_		$I_C = -1.0 \text{mA}, V_{CE} = -5.0 \text{V}$
DC Current Gain (Note 8)	h <sub>FE</sub>	60	240	_	$I_C = -10 \text{mA}, V_{CE} = -5.0 \text{V}$
		50			$I_C = -50 \text{mA}, V_{CE} = -5.0 \text{V}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	-0.2 -0.5	V	$I_C = -10 \text{mA}, I_B = -1.0 \text{mA}$
Concolor Emilior Calaration Voltage					$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$
Base-Emitter Saturation Voltage			-1.0	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA
	V <sub>BE(SAT)</sub>			-	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS	,	1			
Output Capacitance	C <sub>obo</sub>	_	6.0	pF	$V_{CB} = -10V$ , $f = 1.0MHz$ , $I_E = 0$
Small Signal Current Gain	h <sub>fe</sub>	40	200		$V_{CE} = -10V, I_{C} = -1.0mA,$ f = 1.0kHz
Current Gain-Bandwidth Product	f⊤	100	300	MHz	$V_{CE} = -10V, I_{C} = -10mA,$ f = 100MHz
Noise Figure	NF	_	8.0	dB	$V_{CE} = -5.0V$ , $I_{C} = -200\mu A$ , $R_{S} = 10\Omega$ , $f = 1.0kHz$

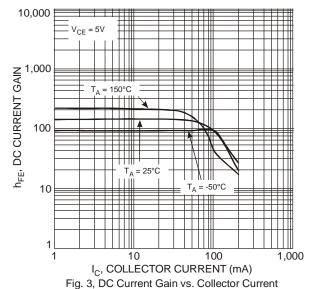
Notes:

- Short duration pulse test used to minimize self-heating effect. The DC Current Gain,  $h_{FE}$ , (matched at  $I_C$  = -10mA and  $V_{CE}$  = -5V) Collector Emitter Saturation Voltage,  $V_{CE(SAT)}$ , and Base Emitter Saturation Voltage,  $V_{BE(SAT)}$  are matched with typical matched tolerances of 1% and maximum of 2%.

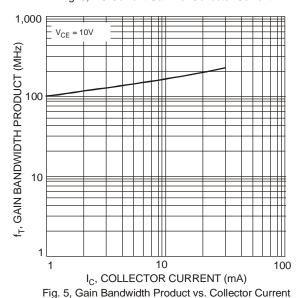








1.0  $V_{BE(ON)}$ , BASE EMITTER VOLTAGE (V) 0.9 T<sub>A</sub> = -50°C 8.0 0.7 0.6 T<sub>A</sub> = 25°C 0.5 0.4  $T_A = 150$ °C 0.3 0.2 0.1  $\begin{array}{c} 1.0 & 10 \\ \text{I}_{\text{C}}, \text{COLLECTOR CURRENT (mA)} \end{array}$ 0.1 100 Fig. 4, Base Emitter Voltage vs. Collector Current

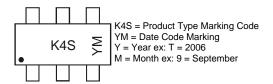


Ordering Information (Note 6 & 9)

Device	Packaging	Shipping
DMMT5401-7-F	SOT-26	3000/Tape & Reel

9. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



Date Code Key

Year	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	R	S	T	U	V	W	Х	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



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